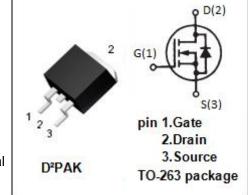


isc N-Channel MOSFET Transistor

PSMN3R4-30BLE

FEATURES

- Drain Current –I_D= 120A@ T_C=25 °C
- · Drain Source Voltage-
 - : V_{DSS}= 30V(Min)
- · Static Drain-Source On-Resistance
 - : $R_{DS(on)} = 3.4 \text{m} \Omega \text{ (Max)}$
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation



DESCRIPTION

• Designed for use in switch mode power supplies and general purpose applications.

ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT
V _{DSS}	Drain-Source Voltage	30	V
V _{GS}	Gate-Source Voltage-Continuous	±20	V
I _D	Drain Current-Continuous	120	А
I _{DM}	Drain Current-Single Pluse	672	Α
P _D	Total Dissipation @T _C =25℃	178	W
TJ	Max. Operating Junction Temperature	-55~175	$^{\circ}$ C
T _{stg}	Storage Temperature	-55~175	$^{\circ}$

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
R _{th j-c}	Thermal Resistance, Junction to Case	0.84	°C/W

	A B D	K	Q	L
J Lie	H_		R	V
		m	m]
	DIM	MIN	MAX]
	Α	1	0	
	В	6.6	6.8	
	C	15.23	15.25]
	D	10.15	10.17]
	F	0.76	0.78]
	G	1.26	1.28 1.6	
	Н	1.4	1.6]
	J	1.33	1.35	
	K	0.4	0.6	
	L	4.6	4.8	
		8.69	8.71	
	Q	0.09		
	R	5.28	5.30]
	-	5.28	5.30 1.28	-
	R	5.28 1.26 0.0	5.30 1.28	
	R	5.28	5.30	

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ELECTRICAL CHARACTERISTICS

Tc=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	MAX	UNIT
V _{(BR)DSS}	Drain-Source Breakdown Voltage	V _{GS} = 0; I _D = 0.25mA	80		V
V _{GS(th)}	Gate Threshold Voltage	V_{DS} = V_{GS} ; I_D = 1mA	1.3	2.15	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} = 10V; I _D = 25A		3.4	mΩ
Igss	Gate-Body Leakage Current	V _{GS} = ±16V;V _{DS} = 0		±100	nA
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} = 30V; V _{GS} = 0		5.0	μА
V _{SD}	Forward On-Voltage	I _S = 25A; V _{GS} = 0		1.2	V

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